

UTC UNISONIC TECHNOLOGIES CO., LTD

01N30

Power MOSFET

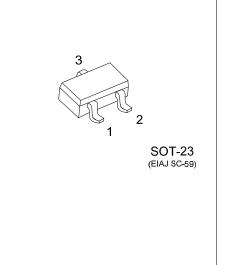
0.1A, 300V N-CHANNEL **POWER MOSFET**

DESCRIPTION

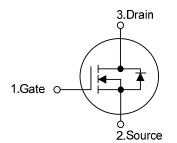
The UTC 01N30 is a planar power MOSFET using UTC's advanced technology to provide customers with a minimum on-state resistance, low gate charge and superior switching performance.

FEATURES

- * $R_{DS(ON)} \le 7.5 \Omega$ @ $V_{GS}=10V$, $I_D=50mA$
- * High switching speed
- * 100% avalanche tested



SYMBOL



ORDERING INFORMATION

Ordering Number		Deekege	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package 1 2 3		Packing			
01N30L-AE3-R	01N30G-AE3-R	SOT-23	G	S	D	Tape Reel	
Note: Pin Assignment: G: Gate S: Source D: Drain							
01N30G-AE3-R (1)Packing Type (2)Package Type (3)Green Package		 (1) R: Tape Reel (2) AE3: SOT-23 (3) G: Halogen Free and Lead Free, L: Lead Free 					

MARKING



■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	300	V
Gate-Source Voltage		V _{GSS}	±30	V
Drain Current	Continuous	ID	0.1	А
	Pulsed (Note 2)	Ідм	0.2	А
Peak Diode Recovery dv/dt (Note 3)		dv/dt	3.7	V/ns
Power Dissipation		PD	0.3	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. Isp \leq 0.1A, di/dt \leq 200A/µs, Vpp \leq BVpss, Starting TJ= 25°C

■ ELECTRICAL CHARACTERISTICS

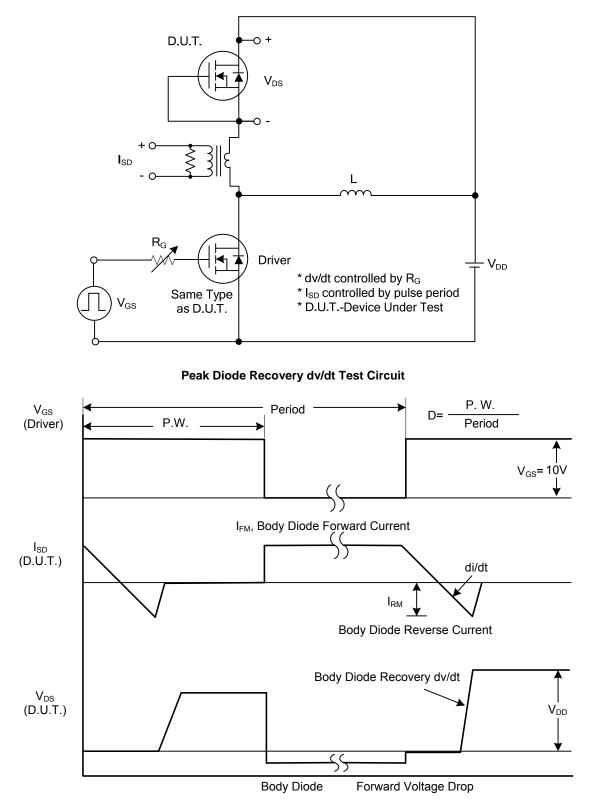
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS			•			
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250µA, V _{DS} =0V	300			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =300V			10	μA
Cata Source Lookage Current	ard	V _{GS} =+30V, V _{DS} =0V			±100	nA
Gate-Source Leakage Current Reve	erse I _{GSS}	V_{GS} =-30V, V_{DS} =0V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	Vds=Vgs, Id=250µA	1.0		3.0	V
Static Drain-Source On-State Resistar	ice R _{DS(ON)}	V _{GS} =10V, I _D =50mA			7.5	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C _{ISS}			70		pF
Output Capacitance	C _{OSS}	V _{GS} =0V, V _{DS} =25V, f=1MHz		15		рF
Reverse Transfer Capacitance	C _{RSS}			3.5		рF
SWITCHING PARAMETERS						
Total Gate Charge	Q_{G}	V _{DS} =240V, V _{GS} =10V, I _D =0.1A (Note1, 2)		9.5		nC
Gate to Source Charge	Q _{GS}			0.7		nC
Gate to Drain Charge	Q _{GD}	(Note 1, 2)		0.3		nC
Turn-ON Delay Time	t _{D(ON)}			2.5		ns
Rise Time	t _R	V _{DS} =100V, V _{GS} =10V, I _D =0.1A,		17		ns
Turn-OFF Delay Time	t _{D(OFF)}	R _G =25Ω (Note1, 2)		28		ns
Fall-Time	t _F			150		ns
SOURCE- DRAIN DIODE RATINGS A	AND CHARACTER	ISTICS				
Maximum Body-Diode Continuous Cur	rrent I _S				0.1	Α
Maximum Body-Diode Pulsed Current	I _{SM}				0.2	Α
Drain-Source Diode Forward Voltage	V _{SD}	I _S =0.1A			1.4	V
Reverse Recovery Time	t _{rr}	V _{GS} =0V, I _S =0.1A,		56		ns
Reverse Recovery Charge	Q _{rr}	dl _F /dt=100A/µs		30		nC
Notes: 1 Pulse Test : Pulse width <30	$0_{\rm He}$ $\overline{D_{\rm He}}$ $v_{\rm He}$ $v_{\rm He}$					

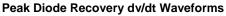
Notes: 1. Pulse Test : Pulse width \leq 300µs, Duty cycle \leq 2%.

2. Essentially independent of operating temperature.



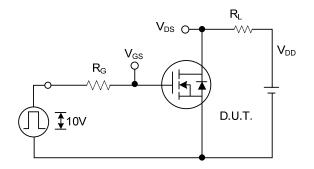
TEST CIRCUITS AND WAVEFORMS



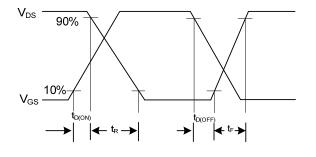




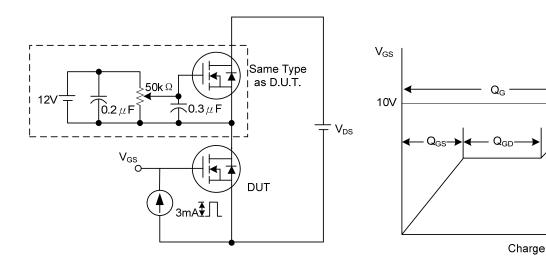
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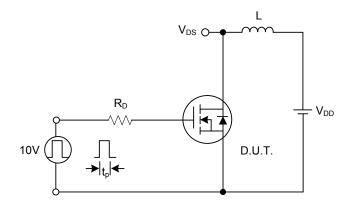


Switching Waveforms

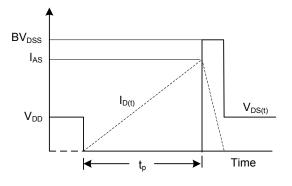


Gate Charge Test Circuit

Gate Charge Waveform



Unclamped Inductive Switching Test Circuit





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